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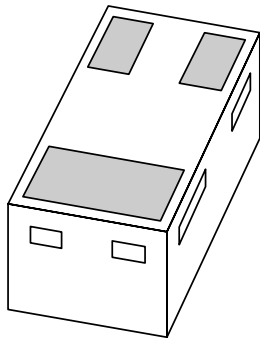
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Kind regards,

Team Nexperia

DATA SHEET



2PC4617M series NPN general purpose transistors

Product data sheet

2003 Jul 15

NPN general purpose transistors

2PC4617M series

FEATURES

- Leadless ultra small plastic package (1 mm × 0.6 mm × 0.5 mm)
- Board space 1.3 × 0.9 mm
- Power dissipation comparable to SOT23.

APPLICATIONS

- General purpose small signal DC applications
- Low and medium frequency AC applications
- Mobile communications, digital (still) cameras, PDAs, PCMCIA cards.

DESCRIPTION

NPN general purpose transistor in a SOT883 leadless ultra small plastic package.

PNP complement: 2PA1776M series.

MARKING

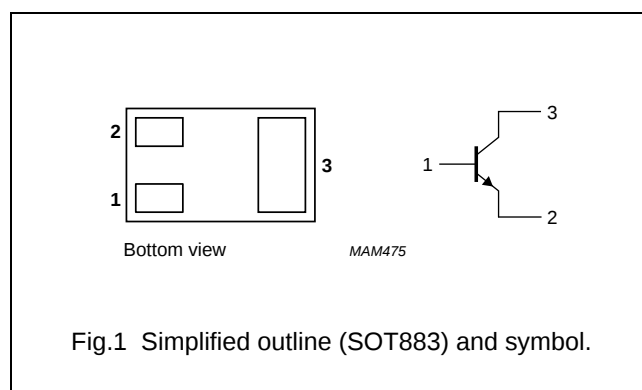
TYPE NUMBER	MARKING CODE
2PC4617QM	D7
2PC4617RM	D8
2PC4617SM	D9

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V_{CEO}	collector-emitter voltage	50	V
I_C	collector current (DC)	100	mA
I_{CM}	peak collector current	200	mA

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	50	V
V_{CEO}	collector-emitter voltage	open base	–	50	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		–	100	mA
I_{CM}	peak collector current		–	200	mA
I_{BM}	peak base current		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$ note 1 note 2	–	250 430	mW mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Notes

1. Refer to SOT883 standard mounting conditions (footprint), FR4 with 60 µm copper strip line.
2. Device mounted on a FR4 printed-circuit board, single-sided copper, mounting pad for collector 1 cm².

NPN general purpose transistors

2PC4617M series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	in free air note 1 note 2	500 290	K/W K/W

Notes

1. Refer to SOT883 standard mounting conditions (footprint), FR4 with 60 μ m copper strip line.
2. Device mounted on a FR4 printed-circuit board, single-sided copper, mounting pad for collector 1 cm².

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector-base cut-off current	$V_{CB} = 30\text{ V}; I_E = 0$	–	100	nA
		$V_{CB} = 30\text{ V}; I_E = 0; T_j = 150\text{ }^{\circ}\text{C}$	–	5	μ A
I_{EBO}	emitter-base cut-off current	$V_{EB} = 4\text{ V}; I_C = 0$	–	100	nA
h_{FE}	DC current gain 2PC4617QM 2PC4617RM 2PC4617SM	$V_{CE} = 6\text{ V}; I_C = 1\text{ mA}$			
			120	270	
			180	390	
			270	560	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 50\text{ mA}; I_B = 5\text{ mA}; \text{note 1}$	–	200	mV
C_c	collector capacitance	$I_E = i_e = 0; V_{CB} = 12\text{ V}; f = 1\text{ MHz}$	–	1.5	pF
f_T	transition frequency	$V_{CE} = 12\text{ V}; I_C = 2\text{ mA};$ $f = 100\text{ MHz}$	100	–	MHz

Note

1. Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.

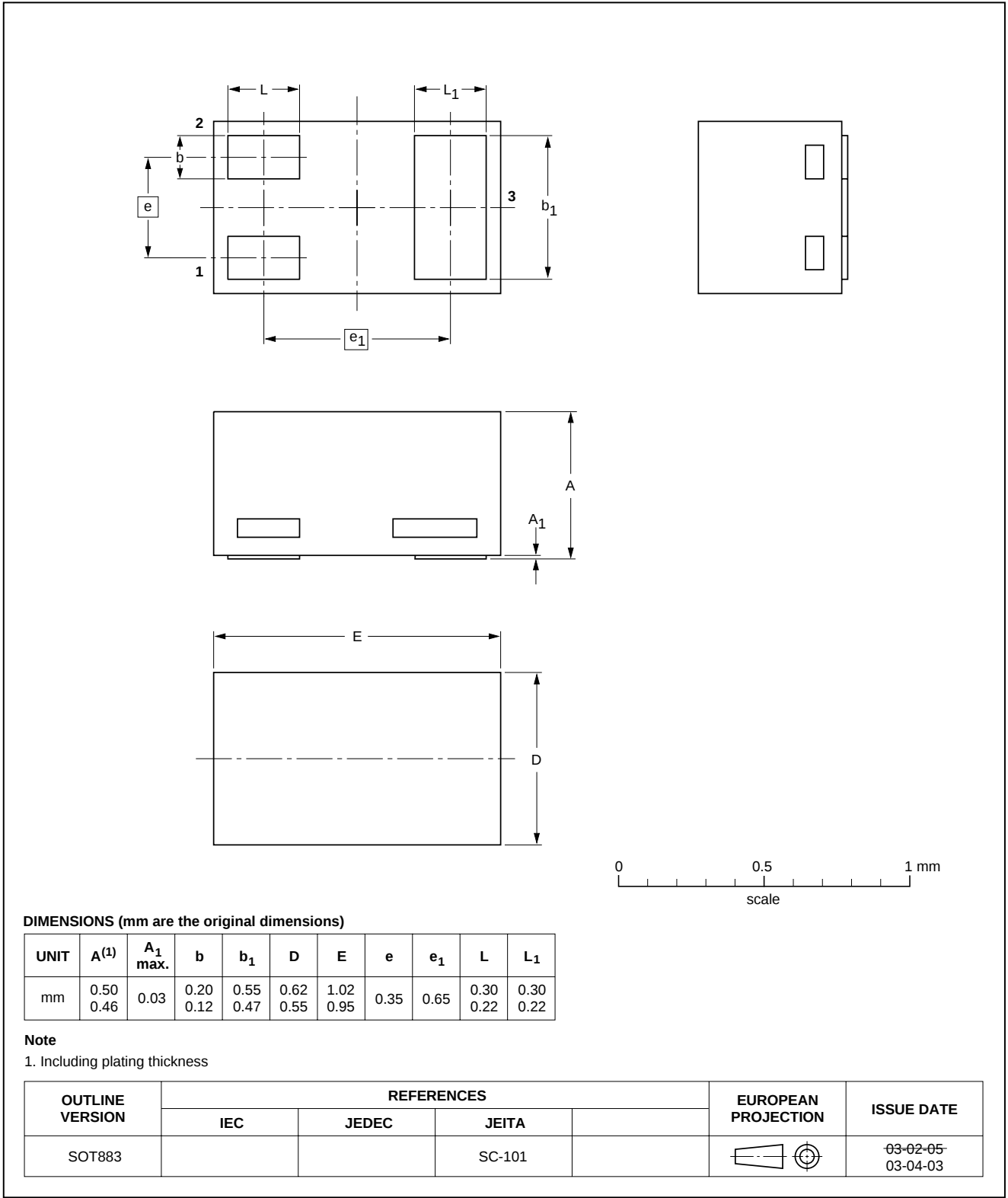
NPN general purpose transistors

2PC4617M series

PACKAGE OUTLINE

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



NPN general purpose transistors

2PC4617M series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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NXP Semiconductors

Customer notification

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Contact information

For additional information please visit: **<http://www.nxp.com>**

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